

Fractional Chern insulators: From higher Chern number

phases to non-Abelian twist defects

Dr. Emil J. Bergholtz

Stockholm University / Freie Universität Berlin

Place:	Room 201a, Faculty of Science Bldg. #1, Hongo Campus,
	Univ. of Tokyo (東大本郷キャンパス理学部1号館 201a 号室)
Date:	August 24 (Thursday), 2017
Time:	13:45-15:00

Abstract:

In this talk I will discuss fractional Chern insulators with emphasis on the analogy with more conventional continuum Landau level physics — and on aspects that are qualitatively new in the lattice setting such as Berry curvature fluctuations, competing instabilities and novel collective states of matter emerging in bands with higher Chern number. I will also explain how the lattice setting naturally allows for exotic extrinsic wormhole-like twist defects (aka "genons") that effectively increase the genus of space.